

High Performance Synchronous Rectifier IC 15mΩ/100V,

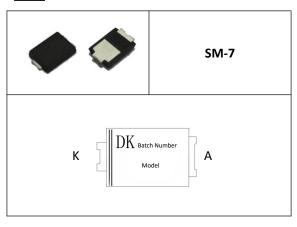
Product Description

DK5V100R15S is a simple but high efficiency synchronous rectifier solution with only two function pins A-K, corresponding A-K pins of Schottky diode. With 100V power NMOS integrated, it can significantly reduce the conduction loss of traditional Schottky diode. Hence it can improve the overall efficiency and replace the same specifications of Schottky rectifier diodes currently on the market. The package of DK5V100R15S is SM-7 (compatible with TO-277).

Product Feature

- Suitable for PSR/SSR feedback mode
- Ultra low VF
- Ultra low temperature rise
- 100V/15mΩ NMOS integrated
- Support CCM/DCM/QR fly-back mode
- Patented self-power supply, no need of external power supply component
- With intelligent detection system, no need of front-end synchronization signal
- Improve EMC/EMI effect
- Replace Schottky Diode directly
- No need of external components

PINS



1

QQ:1248565507

Pins Function

东科半导体原厂

Applications

USB Charger

Adapter LED Driver

etc

No.	Name	Description		
1	К	Same as diode cathode in application		
2	А	Same as diode anode in application		

DK Semiconductor CO., LTD

www.dkpower.cn

DK Semiconductor Proprietary Information. Patent Protected. Unauthorized Photocopy and Duplication Prohibited. © 2020 DK. All Rights Reserved

电话/微信:13751069648

业务联络人:宋政

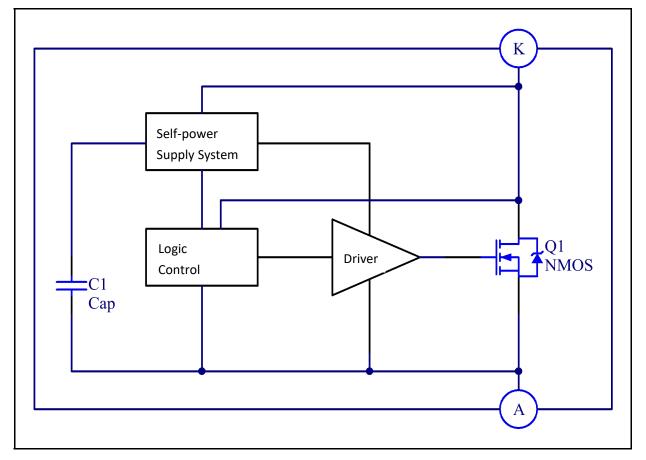


Typical Power

Product Model	Input Voltage	Typical Power		
DK5V100R15S	85-265VAC	12V,3.1A		

Remark: Test typical power in closed environment @45 $^{\circ}$ C ambient temperature. DK5V100R15S system output rated current is recommended not to exceed 3.1A.

东科半导体原厂	业务联络人 : 宋政	电话/微信:13751069648	QQ:1248565507
Functional Struct	<u>ure Diagram</u>		



DK Semiconductor CO., LTD www.dkpower.cn DK Semiconductor Proprietary Information. Patent Protected. Unauthorized Photocopy and Duplication Prohibited. © 2020 DK. All Rights Reserved 东科半导体原厂 业务联络人:宋政 电话/微信:13751069648 QQ:1248565507



Absolute Maximum Rating(All parameters are measured at 25°C ambient)

Note: Exceeding the limit parameters may damage the device. If the device works beyond the limit parameters, it may not work properly and affect the reliability of the device.

Parameter	Symbol	Min	Тур	Max	Unit
NMOS Breakdown Voltage	V _{(BR)DSS}	100			V
NMOS Max. Continuous Current	I _{DSCDC}			40	А
NMOS Max. Peak Current	I _{DSPDC}			60	А
Dissipation power of SM7	P _{DMAX}		1		W
Thermal Resistance (junction to ambient)	Rθ _{JA}		76		°C/W
Thermal Resistance (junction to tube)	Rθ _{JC}		4		°C/W
Case Temperature Range	T _c	-25		120	°C
Storage Temperature Range	T _{STG}	-55		155	°C
Junction Temperature	Tر	-25		150	°C
Soldering Temperature			260/55		°C

Electrical Characteristics $(T_A = 25^{\circ}C)$

东科半导体原厂 业务联络人:宋政

Parameter	Symbol	Condition	Min	Тур	Max	Unit	
Power Supply Section							
V _{CC} Start-up Voltage (1)	V _{CC_ON}			7.2		V	
Undervoltage Protection Threshold $^{(1)}$	V _{CC_uvlo}			3.3		V	
Overvoltage Protection Threshold $^{(1)}$	V _{OVP}			11		V	
Smart Detection and Control Section				•			
NMOS Turn-on Voltage	V _{ON}	K voltage	-210	-213	-216	mV	
NMOS Turn-on Delay	T _{DON}				150	ns	
NMOS Turn-off Delay	TDOFF				50	ns	
NMOS Max. Conduction Duration	T _{ON_MAX}			20	25	μs	
NMOS Min. Conduction Duration	T _{ON_MIN}		166	197	222	ns	
NMOS Min. Turn-off Duration	T _{OFF_MIN}		495	596	686	ns	
Deadtime Duration ^②	T _D			450		ns	
Max. Operating Frequency	Fs_max				150	KHz	
NMOS Section							
NMOS Conduction Resistance	R _{DS_ON}				15	mΩ	

Remarks: (1). Voltages in specification are referenced at pin A.

(2). Deadtime duration can be adjusted automatically based on fluctuation in pin K.

DK Semiconductor CO., LTD www.dkpower.cn

DK Semiconductor Proprietary Information. Patent Protected. Unauthorized Photocopy and Duplication Prohibited. © 2020 DK. All Rights Reserved

电话/微信:13751069648

3



Operation Principle

DK5V100R15S is a simple but high efficiency synchronous rectifier IC with only two function pins, no need of external components. It can significantly reduce the conduction loss of traditional Schottky diode and improve the overall efficiency.

· Start up

DK5V100R15S has patented built-in capacitor for energy storage and self-power supply circuit, which can achieve the driver requirement of the IC and power MOSFET, no need of external power supply. When the voltage of K-point is higher than A-point, Vcc is charged and Vcc voltage increases gradually through self-power supply circuit. When Vcc voltage is lower than starting voltage Vcc_on, the built-in power MOSFET is turned off. When Vcc voltage exceeds Vcc_on, the starting status ends. When Vcc voltage decreases below reset voltage Vcc_uvlo, the synchronous rectifier IC re-enters starting status.

· Power MOSFET control

When the circuit detects the forward voltage of A-K is higher than the turn-on voltage Von, the power MOSFET will be turned on. When it is detected that the current flowing through the power MOSFET decreases to 0 gradually, or when the forward conduction voltage of A-K is 0, the power MOSFET is turned off.

• <u>RC Snubber</u>

During start-up, output short circuit, high input voltage, continuous current mode, etc., it is easy to generate spike voltage across the power MOSFET. To prevent the built-in power MOSFET from overvoltage breakdown, a RC absorption circuit can be connected between A and K to reduce the N-point Spike voltage.

<u>Conduction Resistance of NMOS</u>

东科半导体原厂 业务联络人:宋政

Due to the characteristics of the NMOSFET itself, during operation, the internal resistance will increase and the efficiency will decrease as the temperature rises. Increasing the heat dissipation area appropriately can reduce the operating temperature of the IC.

· Caution!

In the application, the breakdown voltage of the synchronous IC needs to be measured to ensure that the maximum operating voltage of the synchronous rectifier IC is lower than breakdown voltage(VBVDSS). In the application, the temperature of the synchronous IC needs to be measured to evaluate whether the maximum operating temperature of the product exceeds the Operating Junction Temperature.

DK Semiconductor CO., LTD www.dkpower.cn DK Semiconductor Proprietary Information. Patent Protected. Unauthorized Photocopy and Duplication Prohibited. © 2020 DK. All Rights Reserved

电话/微信:13751069648

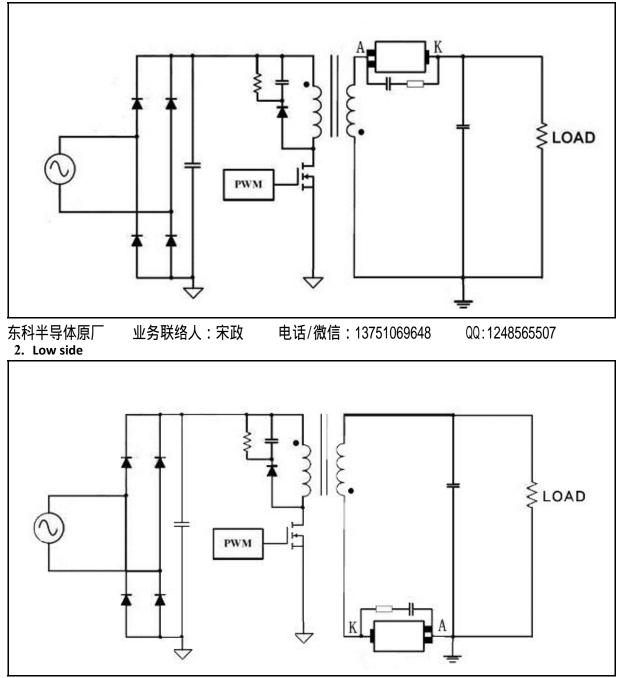


Typical Application Circuit Diagram

1. High side

东科半导体原厂

业务联络人:宋政



DK Semiconductor CO., LTD www.dkpower.cn DK Semiconductor Proprietary Information. Patent Protected. Unauthorized Photocopy and Duplication Prohibited. © 2020 DK. All Rights Reserved

电话/微信:13751069648

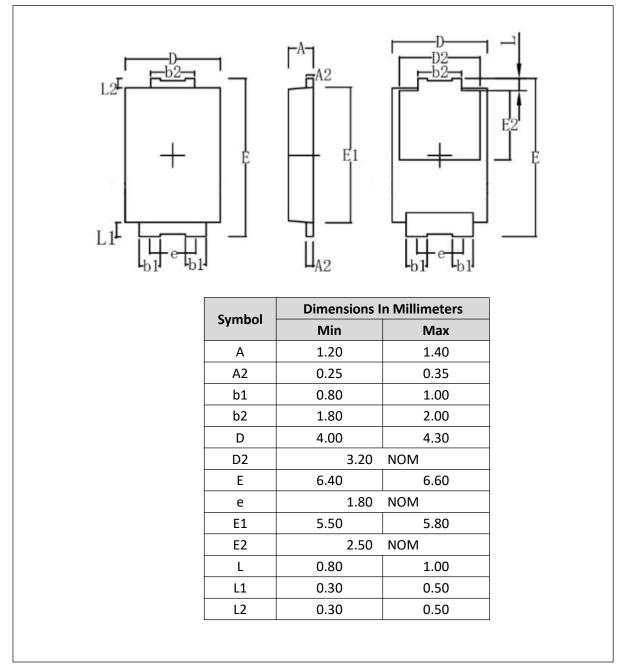


Package and Packing Information

1. SM-7

东科半导体原厂

业务联络人:宋政

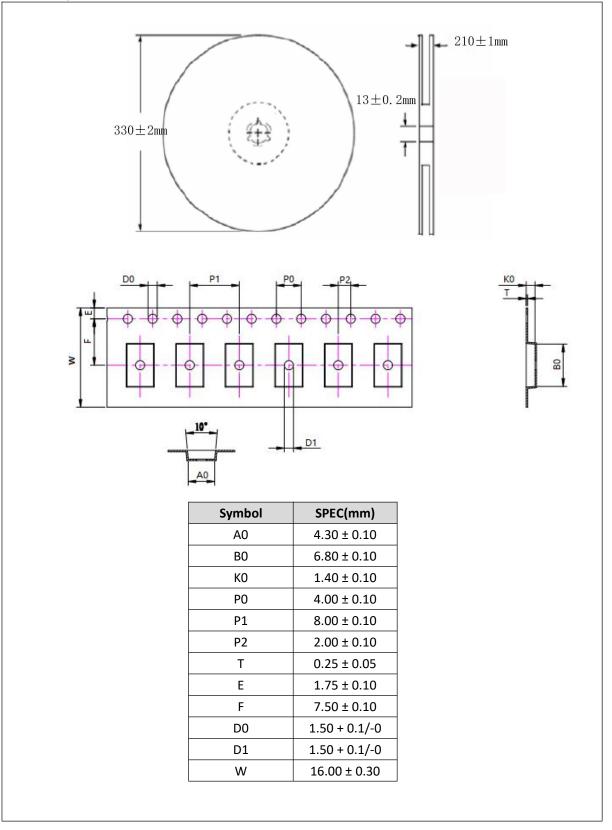


DK Semiconductor CO., LTD www.dkpower.cn DK Semiconductor Proprietary Information. Patent Protected. Unauthorized Photocopy and Duplication Prohibited. © 2020 DK. All Rights Reserved

电话/微信:13751069648



2. Packing Information: 5K/reel



DK Semiconductor CO., LTD www.dkpower.cn DK Semiconductor Proprietary Information. Patent Protected. Unauthorized Photocopy and Duplication Prohibited. © 2020 DK. All Rights Reserved

东科半导体原厂 业务联络人:宋政

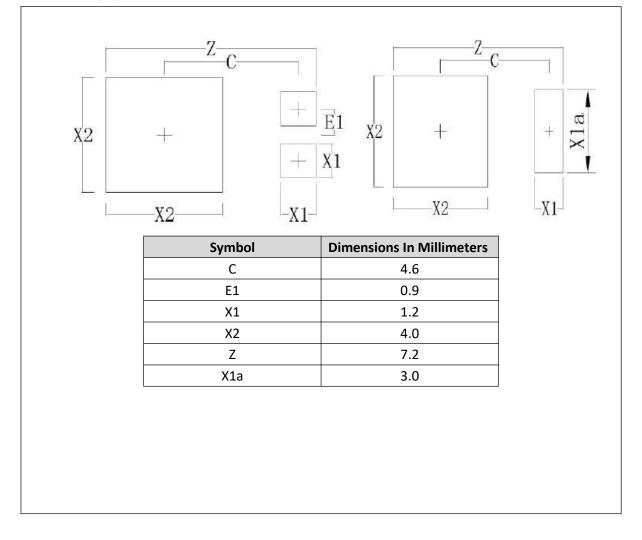
牧 电话/微信:13751069648



东科半导体原厂

DK5V100R15S

3. Welding Specification Reference



DK Semiconductor CO., LTD www.dkpower.cn DK Semiconductor Proprietary Information. Patent Protected. Unauthorized Photocopy and Duplication Prohibited. © 2020 DK. All Rights Reserved

业务联络人:宋政

电话/微信:13751069648





东科半导体原厂

业务联络人:宋政

Caution: This product is a static sensitive component, please pay a attention to protect! The scope of ESD damage can be extended from minor performance to equipment failure. Precision IC may be damaged, which may result in component parameters not meeting the published specifications.

- > Thanks for using our products. We recommend that you read the specifications carefully before using.
- > Dongke Semiconductor Co., Ltd reserves the right of change specifications without prior notice.
- > Dongke Semiconductor Co., Ltd assumes no liability for any use of its products for special purposes.
- > Dongke Semiconductor Co., Ltd has no obligation to support the use and application of products for special purposes.
- > Dongke Semiconductor Co., Ltd will not transfer its patents and any other relevant licensing rights.
- Any semiconductor product may fail or break down under certain conditions. The buyer is responsible to abide by safety standards and take safety measures when designing and manufacturing applications using products of Dongke Semiconductor Co., Ltd to avoid potential failure risk which may cause personal injury or property loss.

电话/微信:13751069648